

Single Phase Rectifier Bridge

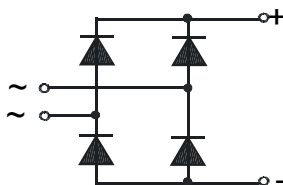
PSB 25

$$I_{dAV} = 21 \text{ A}$$

$$V_{RRM} = 800-1800 \text{ V}$$

Preliminary Data Sheet

V_{RSM} V_{DSM} (V)	V_{RRM} V_{DRM} (V)	Type
800	800	PSB 25/08
1200	1200	PSB 25/12
1400	1400	PSB 25/14
1600	1600	PSB 25/16
1800	1800	PSB 25/18



Symbol	Test Conditions	Maximum Ratings
I_{dAV}	$T_C = 85^\circ\text{C}$, (per module)	17 A
I_{dAVM}	$T_C = 63^\circ\text{C}$, (per module)	21 A
I_{FSM}	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	380 A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	440 A
	$T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine	360 A
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	400 A
$\int i^2 dt$	$T_{VJ} = 45^\circ\text{C}$ $t = 10 \text{ ms}$ (50 Hz), sine	725 A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	800 A ² s
	$T_{VJ} = T_{VJM}$ $t = 10 \text{ ms}$ (50 Hz), sine	650 A ² s
	$V_R = 0$ $t = 8.3 \text{ ms}$ (60 Hz), sine	650 A ² s
T_{VJ}		-40... + 150 °C
T_{VJM}		150 °C
T_{stg}		-40... + 150 °C
V_{ISOL}	50/60 Hz, RMS $t = 1 \text{ min}$	2500 V~
	$I_{ISOL} \leq 1 \text{ mA}$ $t = 1 \text{ s}$	3000 V~
M_d	Mounting torque (M5)	2 Nm
	(10-32 UNF)	18 lb.in.
Weight	typ.	20 g

Symbol	Test Conditions	Characteristic Value
I_R	$V_R = V_{RRM}$, $T_{VJ} = T_{VJM}$	$\leq 0.3 \text{ mA}$
	$V_R = V_{RRM}$, $T_{VJ} = 25^\circ\text{C}$	$\leq 5 \text{ mA}$
V_F	$I_F = 150 \text{ A}$, $T_{VJ} = 25^\circ\text{C}$	$\leq 2.2 \text{ V}$
V_{TO}	For power-loss calculations only	0.85 V
r_T		12 mΩ
R_{thJC}	per diode; DC	8.2 K/W
	per module	2.05 K/W
R_{thJK}	per diode; DC	9.4 K/W
	per module	2.35 K/W
d_s	Creeping distance on surface	12.7 mm
d_A	Creeping distance in air	9.4 mm
a	Max. allowable acceleration	50 m/s ²

Data according to IEC 60747 refer to a single diode unless otherwise stated

Features

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- Package with 1/4" fast-on terminals
- Isolation voltage 3000 V~
- Planar glass passivated chips
- Blocking voltage up to 1800 V
- Low forward voltage drop
- UL registered E 148688

Applications

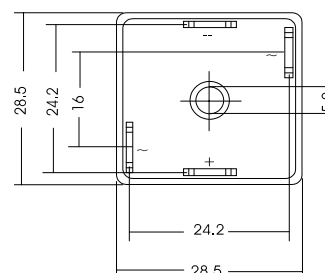
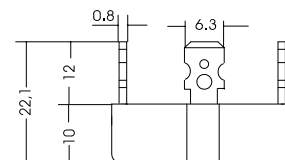
- Supplies for DC power equipment
- Input rectifier for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Advantages

- Easy to mount with one screw
- Space and weight savings
- Improved temperature and power cycling capability

Package style and outline

Dimensions in mm (1mm = 0.0394")



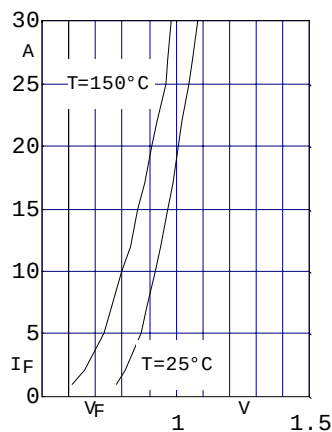


Fig. 1 Forward current versus voltage drop per diode

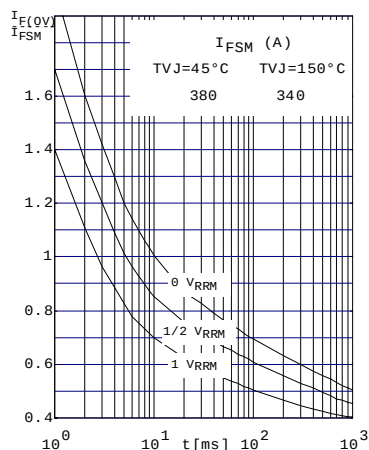


Fig. 2 Surge overload current per diode I_{FSM} : Crest value. t : duration

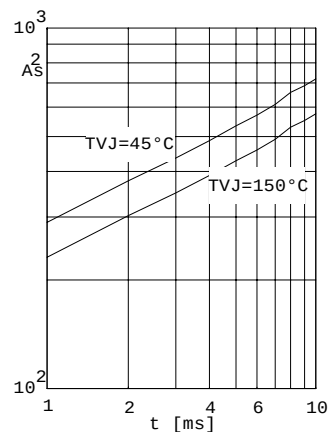


Fig. 3 $\int i^2 dt$ versus time (1-10ms) per diode (or thyristor)

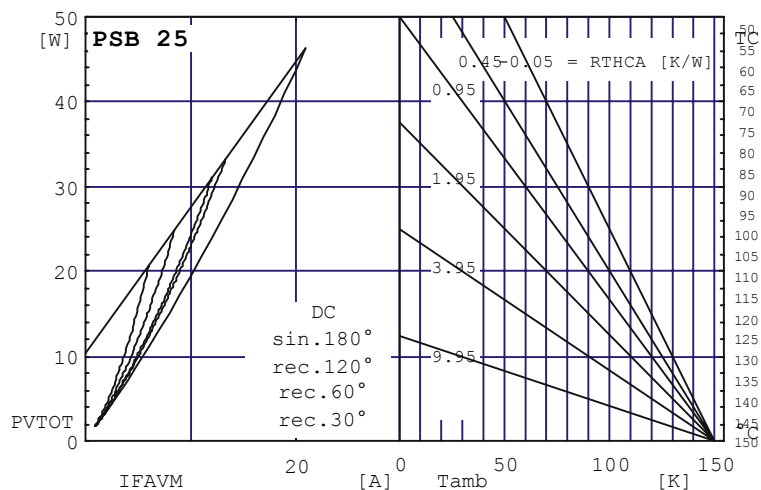


Fig. 4 Power dissipation versus direct output current and ambient temperature

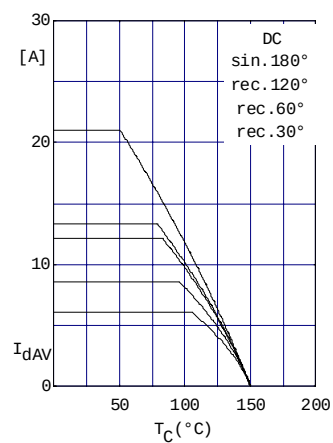


Fig. 5 Maximum forward current at case temperature

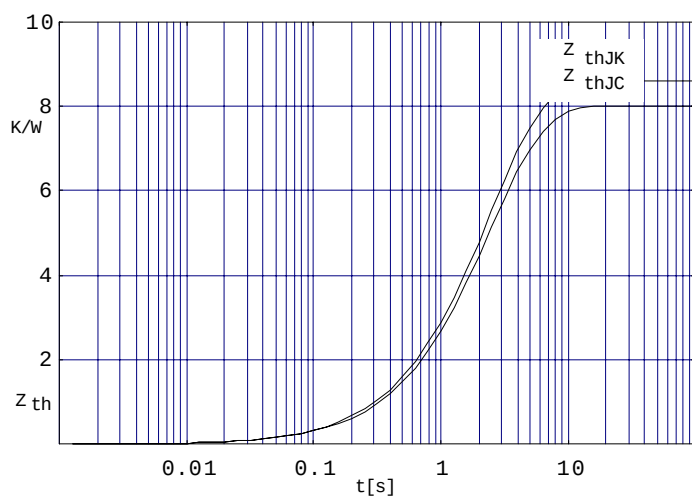


Fig. 6 Transient thermal impedance per diode (or thyristor), calculated